

Notice of References Cited	Application/Control No. 09/479,982	Applicant(s)/Patent Under Reexamination GAUDREAU ET AL.	
	Examiner Roberto J Rios	Art Unit 2836	Page 1 of 1

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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	B	US-4,461,966	07-1984	Hebenstreit, Ernst	327/432
	C	US-6,107,860	08-2000	Vinciarelli, Patrizio	327/427
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	E	US-5,469,041	11-1995	Bourgeois, Jean-Marie	363/134
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	G	US-4,511,815	04-1985	Wood, Peter N.	327/436
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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	"IRF840 HEXFET Power MOSFET Data Sheet", 1997.
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.